

SANYO**SANYO Semiconductors****DATA SHEET**

Diffused Junction Type Silicon Diode

**SVC321 — Varactor Diode (IOCAP)
for AM Receiver Electronic Tuning****Features**

- The SVC321, 321SPA are varactor diodes with a good linearity and high capacitance ratio that is capable of being operated from a low voltage and is intended for use in AM receiver electronic tuning applications.

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

		unit
Reverse Voltage	V_R	-16 V
Junction Temperature	T_j	100 $^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +100 $^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

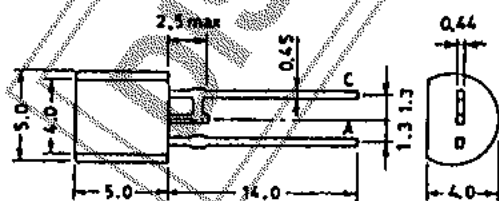
			min	typ	max	unit
Breakdown Voltage	$V_{(BR)R}$	$I_R = -10\mu\text{A}$	-16			V
Reverse Current	I_R	$V_R = -9\text{V}$			-100	nA
Interterminal Capacitance	$C_{1.2\text{V}}$	$V_R = -1.2\text{V}, f = 1\text{MHz}$	388.1		459.1	pF
	$C_{3.5\text{V}}$	$V_R = -3.5\text{V}, f = 1\text{MHz}$	144.2		192.1	pF
	$C_{6.0\text{V}}$	$V_R = -6.0\text{V}, f = 1\text{MHz}$	45.71		60.91	pF
	$C_{8.0\text{V}}$	$V_R = -8.0\text{V}, f = 1\text{MHz}$	20.30		27.05	pF
Quality Factor	Q	$V_R = -1.0\text{V}, f = 1\text{MHz}$	200			
Capacitance Ratio	CR	$C_{1.2\text{V}}/C_{8.0\text{V}}, f = 1\text{MHz}$	15.5			
Matching Tolerance	ΔC_m	$(C_{\text{max}} - C_{\text{min}})/C_{\text{min}}$			0.03	

*: The SVC321, 321SPA are classified by $C_{1.2\text{V}}$ and $C_{8.0\text{V}}$ as follows:

Rank	$C_{1.2\text{V}}$ (pF)	$C_{8.0\text{V}}$ (pF)
A	388.1~424.1	20.30~23.54
B	388.1~424.1	23.31~27.05
C	420.0~459.1	20.30~23.54
D	420.0~459.1	23.31~27.05

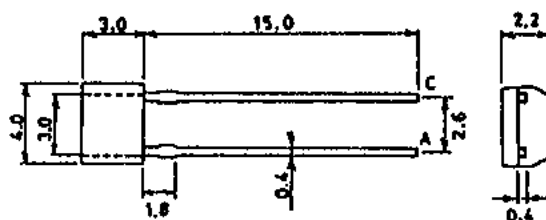
The application circuit diagrams and circuit constants herein are included as an example and provide no guarantee for designing equipment to be mass-produced. The information herein is believed to be accurate and reliable. However, no responsibility is assumed by SANYO for its use, nor for any infringements of patents or other rights of third parties which may result from its use.

Case Outline 1010A [SVC321]
(unit: mm)



C: Cathode
A: Anode

Case Outline 1184 [SVC321SPA]
(unit: mm)



SANYO: SPA

C: Cathode
A: Anode

Specifications and information herein are subject to change without notice.

SANYO Electric Co., Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

3029MO/4088TA/4043KI, TS No.699-1/3

Address and Capacitance Value

TEST POINT	C1.2V		C3.5V		C6.0V		C8.0V	
	(pF)		(pF)		(pF)		(pF)	
	Address	Capacitance	Address	Capacitance	Address	Capacitance	Address	Capacitance
CAPACITANCE VALUE	202	(459.1 445.8)	158	(192.1 186.5)	100	(60.91 59.13)	59	(27.05 26.26)
	201	(450.1 437.0)	157	(188.3 182.8)	99	(59.72 57.98)	58	(26.51 25.74)
	200	(441.3 428.4)	156	(184.6 179.2)	98	(58.54 56.83)	57	(25.99 25.23)
	199	(432.6 420.0)	155	(181.0 175.7)	97	(57.39 55.72)	56	(25.49 24.75)
	198	(424.1 411.7)	154	(177.5 172.3)	96	(56.27 54.64)	55	(24.99 24.26)
	197	(415.8 403.7)	153	(174.0 169.0)	95	(55.17 53.56)	54	(24.49 23.78)
	196	(407.7 395.8)	152	(170.5 165.6)	94	(54.08 52.51)	53	(24.01 23.31)
	195	(399.7 388.1)	151	(167.3 162.4)	93	(53.03 51.48)	52	(23.54 22.86)
			150	(164.0 159.2)	92	(51.98 50.47)	51	(23.08 22.41)
			149	(160.7 156.0)	91	(50.97 49.48)	50	(22.63 21.97)
			148	(157.6 153.0)	90	(49.96 48.51)	49	(22.19 21.54)
			147	(154.4 149.9)	89	(48.99 47.56)	48	(21.75 21.11)
			146	(151.5 147.1)	88	(48.02 46.63)	47	(21.33 20.71)
			145	(148.5 144.2)	87	(47.08 45.71)	46	(20.91 20.30)

Rank and Address Table

08.0V 01.2V	46	47	48	49	50	51	52	53	54	55	56	57	58	59
195														
196														
197														
198														
199														
200														
201														
202														

SVC321,321SPA

